³⁶Si β⁻n decay (503 ms) 1995ReZZ,2017Ha23

Parent: 36 Si: E=0; J $^{\pi}$ =0+; T_{1/2}=503 ms 2; Q(β -n)=4350 70; % β -n decay=12 5

 36 Si-J $^{\pi}$: From Adopted Levels of 36 Si (2012Ni01).

 36 Si- $T_{1/2}$: From 2017Ha23. Others: 0.45 s 6 from Adopted Levels of 36 Si (2012Ni01) taken from 1988DuZS; 0.54 s 21 from 2008ReZZ.

 36 Si-Q(β^- n): From 2021Wa16.

 36 Si- 6 P n decay: From 1995ReZZ,2008ReZZ for the decay of 36 Si. Other: <10 from Adopted Levels of 36 Si (2012Ni01) taken from 1988Mu08.

1995ReZZ,2008ReZZ: fragmentation of 232 Th(p,X) reaction at 800 MeV at LAMPF. Measured $\%\beta^-$ n with ToF isochronous spectrometer.

2017Ha23: ${}^{9}\text{Be}({}^{40}\text{Ar,X})$ E=69.2 MeV/nucleon at HIRFL, Lanzhou. Measured implant- β (t). Deduced $T_{1/2}$.

1988Mu08: fragmentation of 48 Ca at 45 and 55 MeV/nucleon by 181 Ta(48 Ca,X) reaction at GANIL, France. Measured $\%\beta^-$ n<10.

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